

Hyperfast Rectifier, 30 A FRED Pt® G5



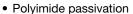
PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V_{R}	1200 V				
V _F at I _F at 125 °C	2.1 V				
t _{rr}	26 ns				
T _J max.	175 °C				
Package	TO-220AC 2L				
Circuit configuration	Single				

FEATURES

- · Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



• 175 °C maximum operating junction temperature



 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



ROHS COMPLIANT HALOGEN FREE

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 90 °C, D = 0.50	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	210	Α			
Repetitive peak forward current	I _{FRM}	T _C = 90 °C, D = 0.50, f = 20 kHz	60				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	1200	-	-		
Forward voltage	V _F	I _F = 30 A	-	2.6	3.15	V	
		I _F = 30 A, T _J = 125 °C	-	2.1	-	,	
Deviates legisare guitant	I _R	$V_R = V_R$ rated	-	-	50	μА	
Reverse leakage current		T _J = 125 °C, V _R = V _R rated	-	-	500		
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF	
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		26	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	100	-	ns	
		T _J = 125 °C		-	150	-	1	
Peak recovery current	1	T _J = 25 °C	$I_F = 20 \text{ A}$ $dI_F/dt = 600 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	12	-	Α	
	I _{RRM}	T _J = 125 °C		-	22	-		
Deviana vacavam debaras	Q _{rr}	T _J = 25 °C		-	530	-	nC	
Reverse recovery charge		T _J = 125 °C		-	1550	-		
Deviana nagavan tima		T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _R = 800 V	-	80	-	ns A	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	120	-		
Dools recovery as weath		T _J = 25 °C		-	22	-		
Peak recovery current	I _{RRM}	T _J = 125 °C		-	37	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	900	-	nC	
		T _J = 125 °C		-	2300	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.2	°C/W	
Weight			-	2.0	-	g	
			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style: 2L TO-220AC	E5TX3012				

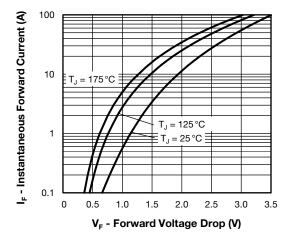


Fig. 1 - Typical Forward Voltage Drop Characteristics

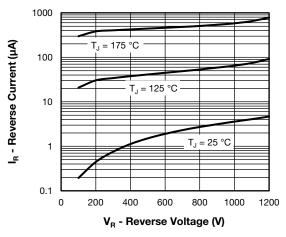


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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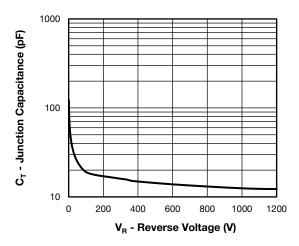


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

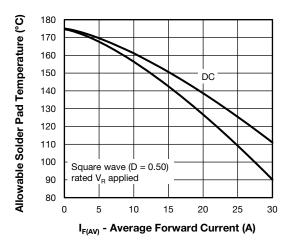


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

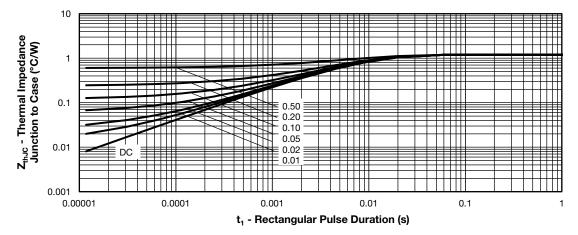


Fig. 5 - Thermal Impedance Z_{thJC} Characteristics

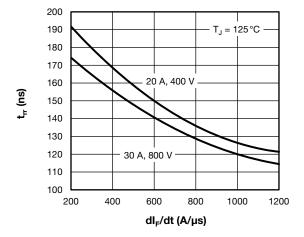


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

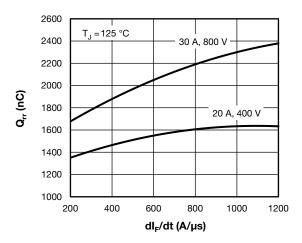


Fig. 7 - Typical Stored Charge vs. dl_F/dt

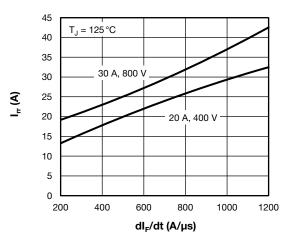


Fig. 8 - Typical Recovery Current vs. dl_F/dt

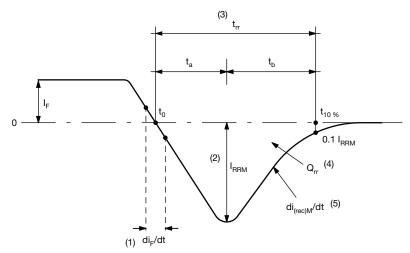


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ Q_{rr} area under curve defined by t_0 and $t_{10\,\%}$

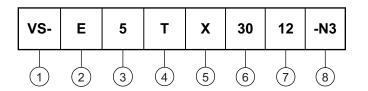
$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - E = single diode

3 - 5 = Fred generation 5

4 - Package:

T = TO-220AC 2L

5 - X = hyperfast recovery

6 - Current rating (30 = 30 A)

7 - Voltage rating (12 = 1200 V)

8 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

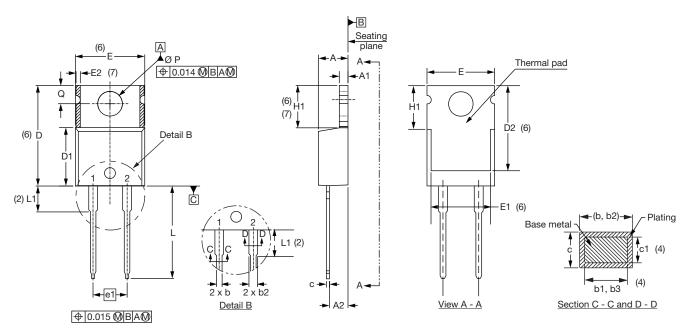
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-E5TX3012-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96069				
Part marking information	www.vishay.com/doc?95391				
SPICE model	www.vishay.com/doc?96701				



2L TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES	
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e1	4.88	5.28	0.192	0.208	
H1	5.84	6.86	0.230	0.270	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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